

#### Performance characteristics

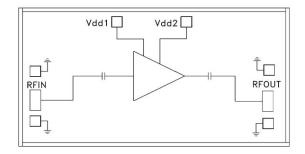
Frequency range: 12-20GHz
Small signal gain: 18dB
Noise figure: 1.8dB typ.
Noise figure: 2.4dB max.

P-1dB: 17dBm

Power supply: +5V/60mA
Input/Output: 50Ohm
100% on-chip testing

Chip size: 2.0 x 1.0 x 0.1 mm

## Functional Block Diagram



### **Product Introduction**

GLA-1220-1.8 is a broadband low-noise amplifier chip, with a frequency range of 12GHz~20GHz, a small signal gain of 18dB, and an in band noise figure of 1.8dB. GLA-1220-1.8 uses+5V single power supply.

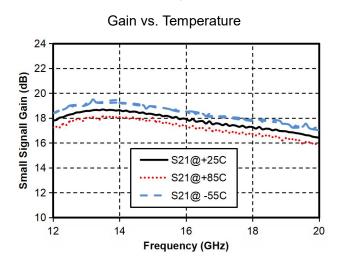
Use restriction parameters <sup>1</sup>				
Maximum leakage voltage	+7V			
Maximum input power	+20dBm			
Working temperature	-55 ~ +85°C			
Storage temperature	-65 ~ +150°C			

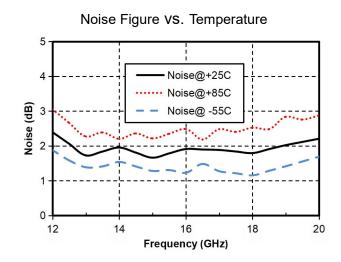
[1] Exceeding any of the above maximum limits may result in permanent damage.

Electrical performance parameters(T <sub>A</sub> = +25°C, Vd=+5V)							
Index	Minimum value	Typical value	Maximum value	Unit			
Frequency range	12-20			GHz			
Small signal gain	16.5	18	18.5	dB			
Gain flatness		±1.0		dB			
Noise figure	1.6	1.8	2.4	dB			
P-1dB	13.5	17	18.5	dBm			
OIP3	24.5	27	28.2	dBm			
Input return loss		10		dB			
Output return Loss		12		dB			
Static current		60		mA			

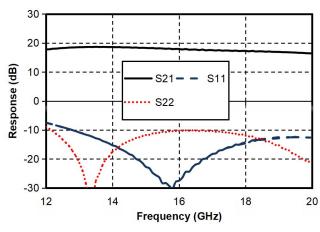


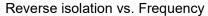
## Main indicator testing curve

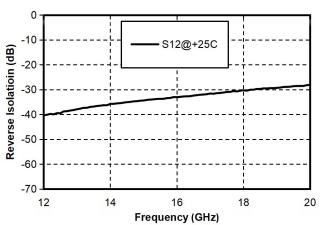




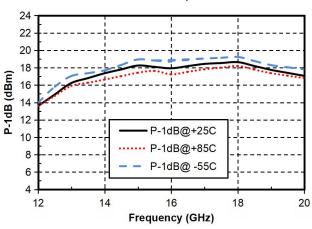
Gain&Input/Output Return Loss vs. Frequency



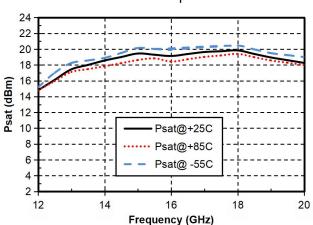




P-1dB vs. Temperature

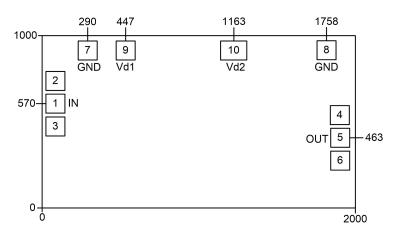


Psat vs. Temperature





## External structure<sup>2</sup>

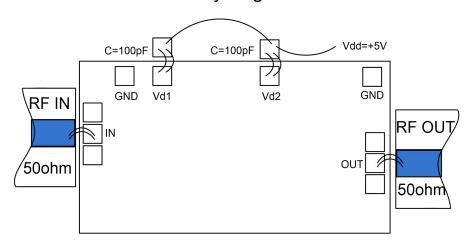


[2] The units in the figure are all millimeters.

Definition of bonding pressure point					
Bond point number	Functional symbols	Function Description	Equivalent circuit		
1	RFIN	RF signal input terminal, no need for DC capacitors.	RF IN		
5	RFOUT	RF signal output terminal, no need for DC isolation capacitor.	RF OUT		
9	Vd1	Amplifier drain bias, requires an external 100pF bypass capacitor.	Vdd		
10	Vd2	Amplifier drain bias, requires an external 100pF bypass capacitor.	Vdd -		
2, 3, 4, 6, 7, 8	GND	Grounding point for probe testing.	ONO		
Chip bottom	GND	The bottom of the chip needs to be well grounded with RF and DC.	OND		



## Recommended assembly diagram



#### **Notice**

- The chip needs to be stored in a container with anti-static function and stored in a nitrogen environment.
- Attempting to clean the surface of bare chips using wet chemical methods is prohibited.
- Please strictly comply with ESD protection requirements to avoid static damage to bare chips.
- Routine operation: Please use precision pointed tweezers to remove the bare chip. During the operation, avoid tools or fingers touching the surface of the chip.
- Suggestion for mounting operation: Bare chip installation can use AuSn solder eutectic sintering or conductive adhesive bonding process. The installation surface must be clean and flat.
- Sintering process: It is recommended to use AuSn solder sheets with a gold tin ratio of 80/20. The working surface temperature reached 255 °C, and the tool (vacuum chuck) temperature reached 265 °C. When a high-temperature mixed gas (nitrogen to hydrogen ratio of 90/10) is blown onto the chip, the temperature at the top of the tool should be raised to 290 °C. Do not let the chip stay above 320 °C for more than 20 seconds. The friction time should not exceed 3 seconds.
- Bonding process: The amount of conductive adhesive applied should be as small as possible.
   After placing the chip in the installation position, the conductive adhesive can be vaguely visible around it. Please follow the information provided by the conductive adhesive manufacturer for curing conditions.
- Suggestion for bonding operation: Both spherical or wedge-shaped bonding should be used Φ 0.025mm (1mil) gold wire. Thermal ultrasonic bonding temperature is 150 °C. The pressure of the spherical bonding cutter is 40-50GF, and the pressure of the wedge bonding cutter is 18-22GF. Use as little ultrasonic energy as possible. The bonding process starts at the pressing point on the chip and ends at the packaging (or substrate).

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